NSN 5961-00-882-2275

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-882-2275 **Inclosure Material:** Glass **Overall Length:** 0.520 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.260 inches **End Application:** Mcs mine countermeasures; forrestal class cv; nimitz class cvn; air conditioner (a/e32c-39); tarawa class lha; two jima class lph; an/spn-43b, 43c **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.3 regulator voltage, dc **Voltage Tolerance In Percent:** -0.002/+0.002 **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** Weapon system essential; junction pattern arrangement: pn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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Yes - demil/mli